

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	2891	semiconductor and (dmos or (vertical adj (dmos or mos or mosfet or fet)))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB	2001/10/19 10:33
2	BRS	L2	2011	1 and source and drain	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB	2001/10/19 10:36
3	BRS	L3	87	2 and (schottky adj diode)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB	2001/10/19 10:37

	Comments	Error Definition	Errors
1			0
2			0
3			0